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# **MB05S THRU MB10S**

#### SINGLE-PHASE GLASS PASSIVATED SILICON SURFACE MOUNT BRIDGE RECTIFIER

### REVERSE VOLTAGE: FORWARD CURRENT:

50 to 1000 VOLTS 1.0 AMPERE

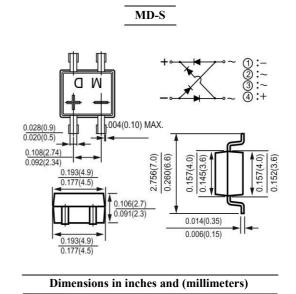
#### **FEATURES**

 $\cdot$  Glass passivated chip junction

- $\cdot$  Low forward voltage drop
- $\cdot$  High surge overload rating of 50 Amperes peak
- $\cdot$  Ideal for printed circuit board
- · High temperature soldering guaranteed:
- 260°C for 10 seconds

#### MECHANICAL DATA

Case: Molded plastic, DB-S Epoxy: UL 94V-O rate flame retardant Terminals: Leads solderable per MIL-STD-202, method 208 guaranteed Mounting position: Any Weight: 0.008ounce, 0.22gram



#### Maximum Ratings and Electrical Characteristics

Ratings at 25℃ ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

|   | Symbols             | MB05S      | MB1S | MB2S | MB4S       | MB6S | MB8 S | MB10S | Units |
|---|---------------------|------------|------|------|------------|------|-------|-------|-------|
| Maximum Recurrent Peak Reverse Voltage  | VRRM                | 50         | 100  | 200  | 400        | 600  | 800   | 1000  | Volts |
| Maximum RMS Voltage   | V<br>RMS            | 35         | 70   | 140  | 280        | 420  | 560   | 700   | Volts |
| Maximum DC Blocking Voltage   | VDC                 | 50         | 100  | 200  | 400        | 600  | 800   | 1000  | Volts |
| Maximum Average Forward<br>Rectified Current at TA=40°C (Note 2)  | I(AV)               |            |      |      | 1.0        |      |       |       | Amp   |
| Peak Forward Surge Current,<br>8.3ms single half-sine-wave<br>superimposed on rated load (JEDEC method) | I<br><sub>FSM</sub> | 50         |      |      |            |      |       |       | Атр   |
| Maximum Forward Voltage<br>at 1.0A DC and 25℃   | VF                  | 1.1        |      |      |            |      |       |       | Volts |
| Maximum Reverse Currentat TA=25°Cat Rated DC Blocking VoltageTA=125°C                                   | I <sub>R</sub>      | 5.0<br>500 |      |      |            |      |       |       | uAmp  |
| Typical Junction Capacitance (Note 1)   | CJ                  | 25         |      |      |            |      |       |       | pF    |
| Typical Thermal Resistance (Note 2)   | Rөја                | 40         |      |      |            |      |       |       | °C/W  |
| Typical Thermal Resistance (Note 2)   | R<br><sub>ØJL</sub> |            |      |      | 15         |      |       |       | °C/W  |
| Operating and Storage Temperature Range   | TJ, Tstg            |            |      | -    | 55 to +150 | )    |       |       | °C    |

#### NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Units mounted on P.C.B. with 0.5 x 0.5" (13 x 13mm) copper pads

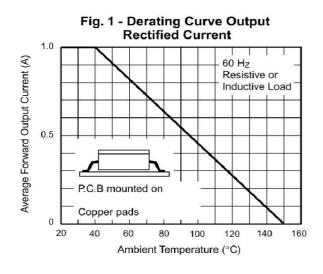


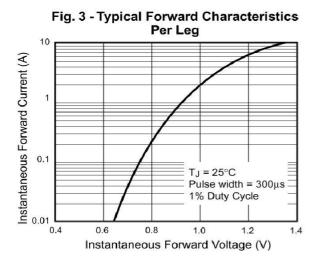
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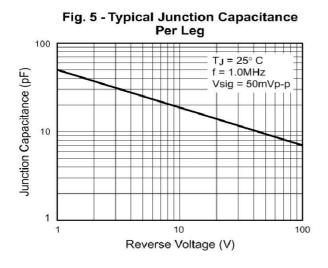
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## RATINGS AND CHARACTERISTIC CURVES







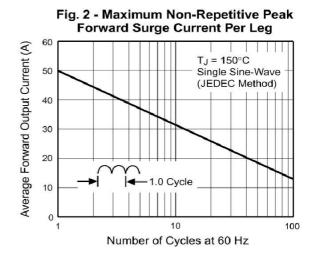


Fig. 4 - Typical Reverse Leakage Characteristics Per Leg

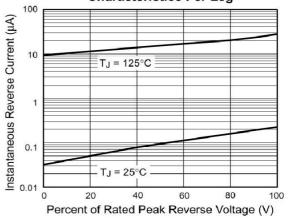


Fig. 6 - Typical Transient Thermal Impedance

